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MUN2111T1 Series

Preferred Devices

Bias Resistor Transistors

PNP Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-59 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Moisture Sensitivity Level: 1
- ESD Rating – Human Body Model: Class 1
– Machine Model: Class B
- The SC-59 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
- Available in 8 mm embossed tape and reel
Use the Device Number to order the 7 inch/3000 unit reel.

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V_{CB0}	50	Vdc
Collector-Emitter Voltage	V_{CEO}	50	Vdc
Collector Current	I_C	100	mAdc

THERMAL CHARACTERISTICS

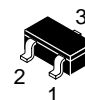
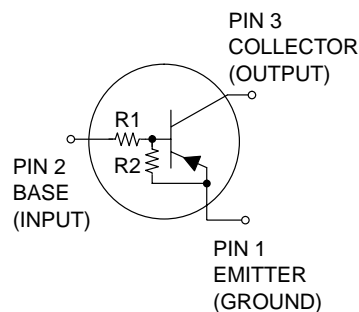
Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	230 (Note 1) 338 (Note 2) 1.8 (Note 1) 2.7 (Note 2)	mW $^\circ\text{C/W}$
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	540 (Note 1) 370 (Note 2)	$^\circ\text{C/W}$
Thermal Resistance – Junction-to-Lead	$R_{\theta JL}$	264 (Note 1) 287 (Note 2)	$^\circ\text{C/W}$
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

1. FR-4 @ Minimum Pad
2. FR-4 @ 1.0 x 1.0 inch Pad



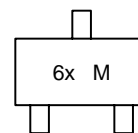
ON Semiconductor®

<http://onsemi.com>



SC-59
CASE 318D
PLASTIC

MARKING DIAGRAM



6x = Specific Device Code*
M = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

DEVICE MARKING INFORMATION

*See device marking table on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MUN211T1 Series

DEVICE MARKING AND RESISTOR VALUES

Device	Package	Marking	R1 (K)	R2 (K)	Shipping
MUN2111T1	SC-59	6A	10	10	3000/Tape & Reel
MUN2112T1	SC-59	6B	22	22	3000/Tape & Reel
MUN2113T1	SC-59	6C	47	47	3000/Tape & Reel
MUN2114T1	SC-59	6D	10	47	3000/Tape & Reel
MUN2115T1 (Note 3)	SC-59	6E	10	∞	3000/Tape & Reel
MUN2116T1 (Note 3)	SC-59	6F	4.7	∞	3000/Tape & Reel
MUN2130T1 (Note 3)	SC-59	6G	1.0	1.0	3000/Tape & Reel
MUN2131T1 (Note 3)	SC-59	6H	2.2	2.2	3000/Tape & Reel
MUN2132T1 (Note 3)	SC-59	6J	4.7	4.7	3000/Tape & Reel
MUN2133T1 (Note 3)	SC-59	6K	4.7	47	3000/Tape & Reel
MUN2134T1 (Note 3)	SC-59	6L	22	47	3000/Tape & Reel
MUN2136T1	SC-59	6N	100	100	3000/Tape & Reel
MUN2137T1	SC-59	6P	47	22	3000/Tape & Reel
MUN2140T1 (Note 3)	SC-59	6T	47	∞	3000/Tape & Reel

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector-Base Cutoff Current (V _{CB} = 50 V, I _E = 0)	I _{CBO}	-	-	100	nAdc
Collector-Emitter Cutoff Current (V _{CE} = 50 V, I _B = 0)	I _{CEO}	-	-	500	nAdc
Emitter-Base Cutoff Current (V _{EB} = 6.0 V, I _C = 0)	MUN2111T1	-	-	0.5	mAdc
	MUN2112T1	-	-	0.2	
	MUN2113T1	-	-	0.1	
	MUN2114T1	-	-	0.2	
	MUN2115T1	-	-	0.9	
	MUN2116T1	-	-	1.9	
	MUN2130T1	-	-	4.3	
	MUN2131T1	-	-	2.3	
	MUN2132T1	-	-	1.5	
	MUN2133T1	-	-	0.18	
	MUN2134T1	-	-	0.13	
	MUN2136T1	-	-	0.05	
	MUN2137T1	-	-	0.13	
MUN2140T1	-	-	0.20		
Collector-Base Breakdown Voltage (I _C = 10 μA, I _E = 0)	V _{(BR)CBO}	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (Note 4) (I _C = 2.0 mA, I _B = 0)	V _{(BR)CEO}	50	-	-	Vdc

3. New resistor combinations. Updated curves to follow in subsequent data sheets.

4. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%

MUN211T1 Series

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS (Note 5)						
DC Current Gain (V _{CE} = 10 V, I _C = 5.0 mA)	MUN2111T1	h _{FE}	35	60	–	
	MUN2112T1		60	100	–	
	MUN2113T1		80	140	–	
	MUN2114T1		80	140	–	
	MUN2115T1		160	250	–	
	MUN2116T1		160	250	–	
	MUN2130T1		3.0	5.0	–	
	MUN2131T1		8.0	15	–	
	MUN2132T1		15	27	–	
	MUN2133T1		80	140	–	
	MUN2134T1		80	130	–	
	MUN2136T1		80	150	–	
	MUN2137T1		80	140	–	
	MUN2140T1		120	250	–	
Collector–Emitter Saturation Voltage (I _C = 10 mA, I _B = 0.3 mA) (I _C = 10 mA, I _B = 5.0 mA) (I _C = 10 mA, I _B = 1.0 mA)	MUN2111T1	V _{CE(sat)}	–	–	0.25	Vdc
	MUN2112T1		–	–	0.25	
	MUN2113T1		–	–	0.25	
	MUN2114T1		–	–	0.25	
	MUN2115T1		–	–	0.25	
	MUN2130T1		–	–	0.25	
	MUN2136T1		–	–	0.25	
	MUN2137T1		–	–	0.25	
	MUN2131T1		–	–	0.25	
	MUN2116T1		–	–	0.25	
	MUN2132T1		–	–	0.25	
	MUN2134T1		–	–	0.25	
	MUN2140T1		–	–	0.25	
	Output Voltage (on) (V _{CC} = 5.0 V, V _B = 2.5 V, R _L = 1.0 kΩ) (V _{CC} = 5.0 V, V _B = 3.5 V, R _L = 1.0 kΩ) (V _{CC} = 5.0 V, V _B = 5.5 V, R _L = 1.0 kΩ) (V _{CC} = 5.0 V, V _B = 4.0 V, R _L = 1.0 kΩ)		MUN2111T1	V _{OL}	–	
MUN2112T1		–	–		0.2	
MUN2114T1		–	–		0.2	
MUN2115T1		–	–		0.2	
MUN2116T1		–	–		0.2	
MUN2130T1		–	–		0.2	
MUN2131T1		–	–		0.2	
MUN2132T1		–	–		0.2	
MUN2133T1		–	–		0.2	
MUN2134T1		–	–		0.2	
MUN2113T1		–	–		0.2	
MUN2140T1		–	–		0.2	
MUN2136T1		–	–		0.2	
MUN2137T1		–	–		0.2	

5. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%

MUN211T1 Series

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit	
ON CHARACTERISTICS (Note 6) (Continued)						
Output Voltage (off) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.050\text{ V}$, $R_L = 1.0\text{ k}\Omega$) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.25\text{ V}$, $R_L = 1.0\text{ k}\Omega$)	V_{OH}	4.9	–	–	Vdc	
Input Resistor	MUN2111T1 MUN2112T1 MUN2113T1 MUN2114T1 MUN2115T1 MUN2116T1 MUN2130T1 MUN2131T1 MUN2132T1 MUN2140T1	R1	7.0 15.4 32.9 7.0 7.0 3.3 0.7 1.5 3.3 3.3 15.4 70 32.9 32.9	10 22 47 10 10 4.7 1.0 2.2 4.7 4.7 22 100 47 47	13 28.6 61.1 13 13 6.1 1.3 2.9 6.1 6.1 28.6 130 61.1 61.1	k Ω
Resistor Ratio	MUN2111T1/MUN2112T1/MUN2113T1/ MUN2136T1 MUN2114T1 MUN2115T1/MUN2116T1/MUN2140T1 MUN2130T1/MUN2131T1/MUN2132T1 MUN2133T1 MUN2134T1 MUN2137T1	R_1/R_2	0.8 0.17 – 0.8 0.055 0.38 1.7	1.0 0.21 – 1.0 0.1 0.47 2.1	1.2 0.25 – 1.2 0.185 0.56 2.6	

6. Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%

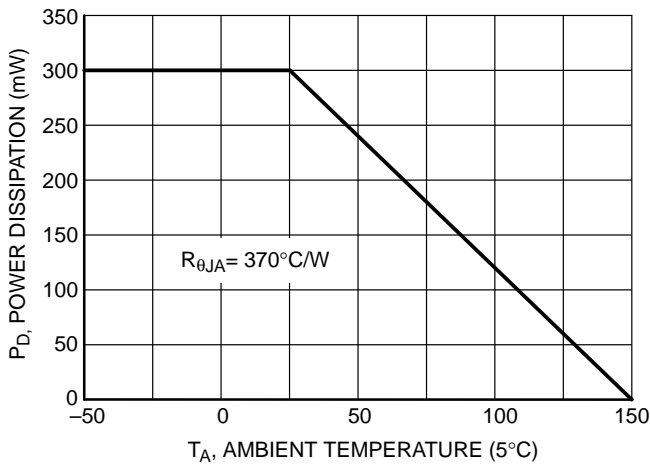


Figure 1. Derating Curve

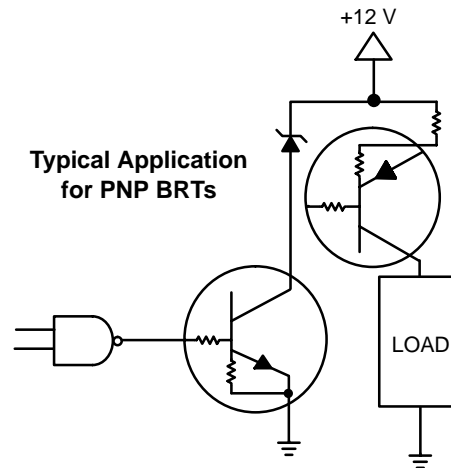


Figure 2. Inexpensive, Unregulated Current Source

MUN211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN211T1

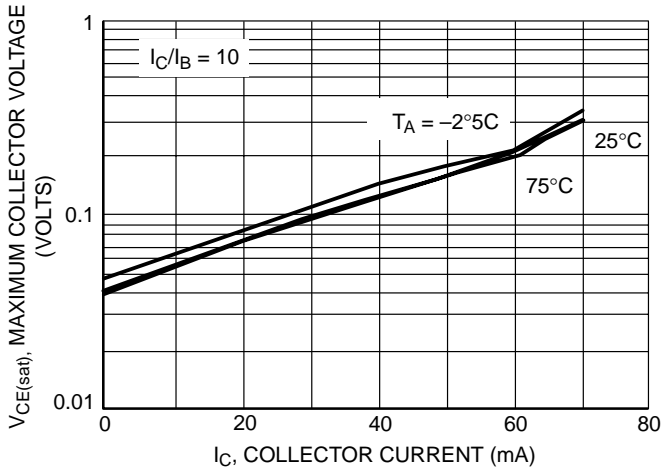


Figure 3. $V_{CE(sat)}$ vs. I_C

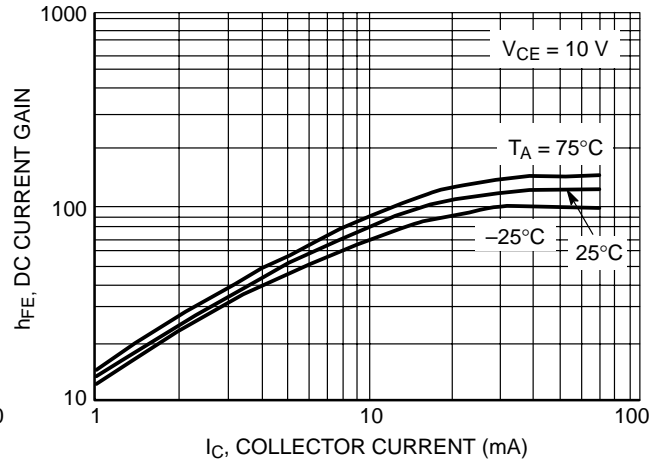


Figure 4. DC Current Gain

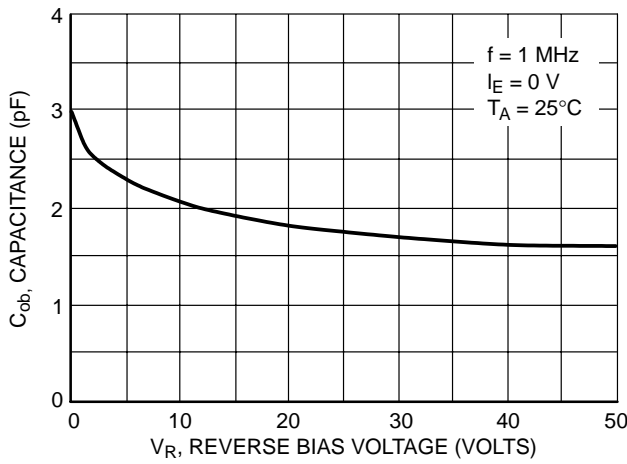


Figure 5. Output Capacitance

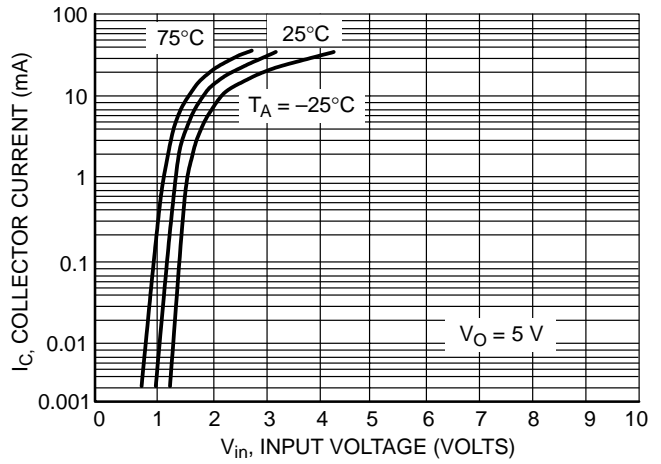


Figure 6. Output Current vs. Input Voltage

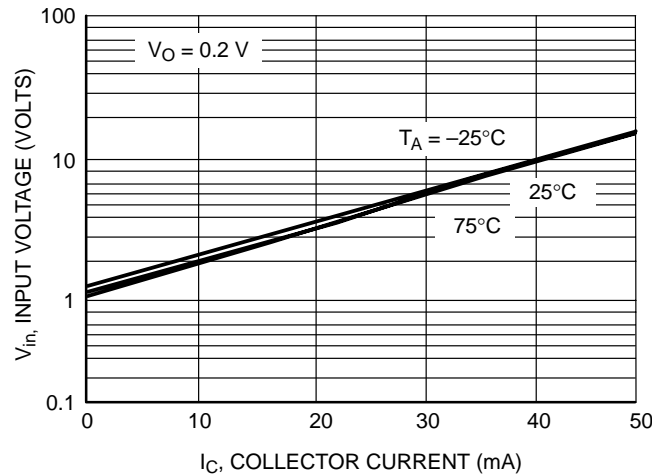


Figure 7. Input Voltage vs. Output Current

MUN211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2112T1

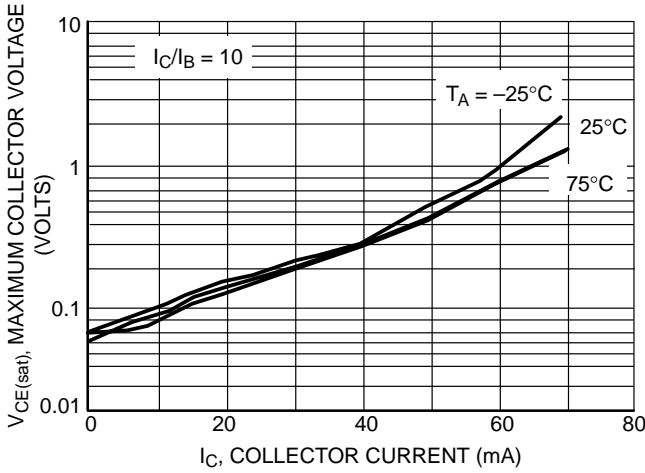


Figure 8. $V_{CE(sat)}$ vs. I_C

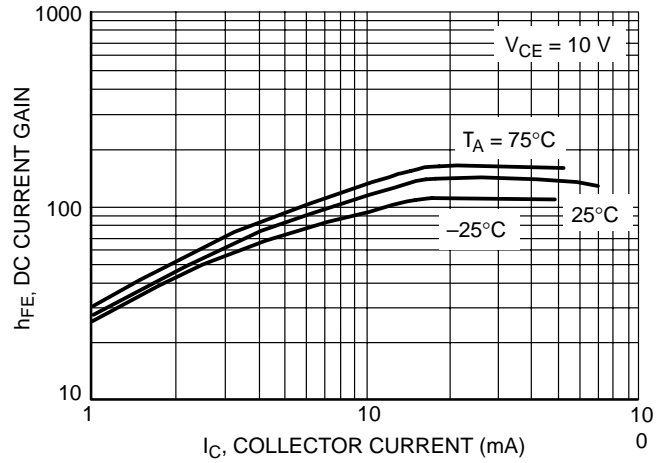


Figure 9. DC Current Gain

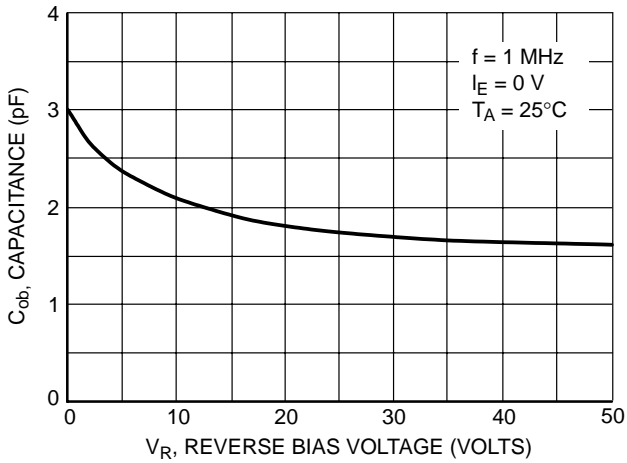


Figure 10. Output Capacitance

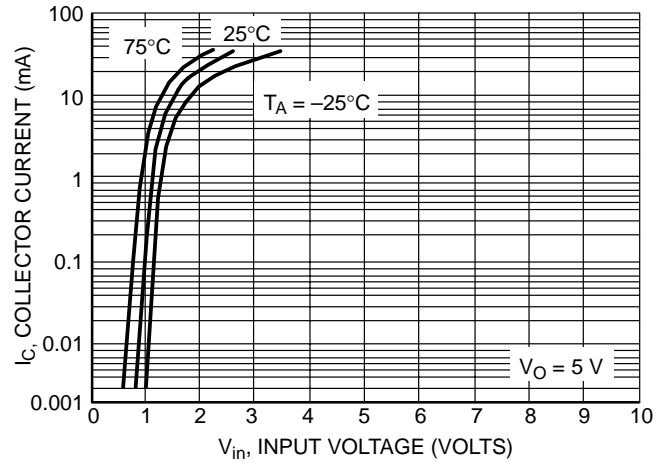


Figure 11. Output Current vs. Input Voltage

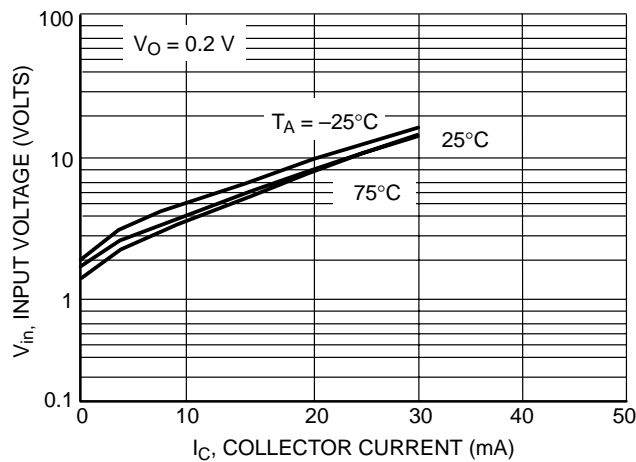


Figure 12. Input Voltage vs. Output Current

MUN211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2113T1

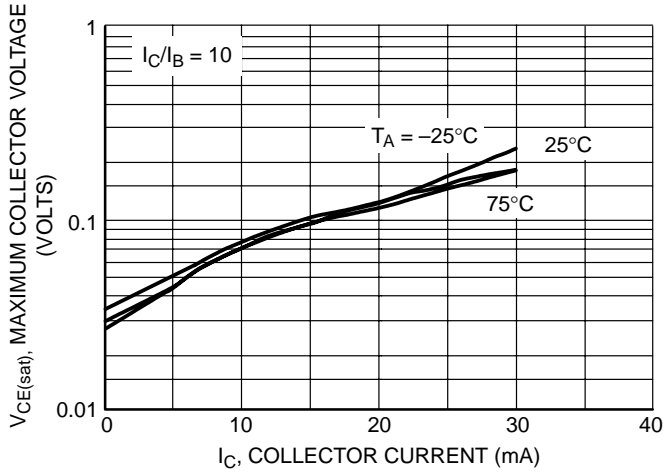


Figure 13. $V_{CE(sat)}$ vs. I_C

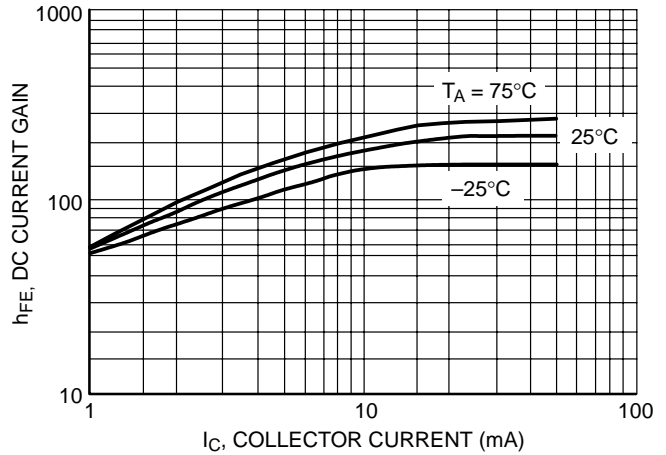


Figure 14. DC Current Gain

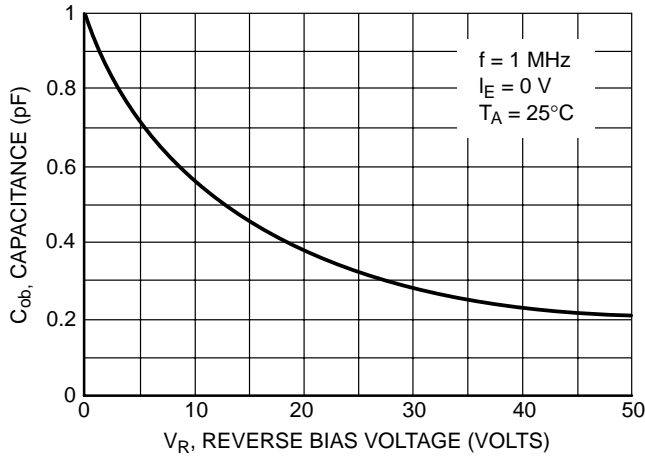


Figure 15. Output Capacitance

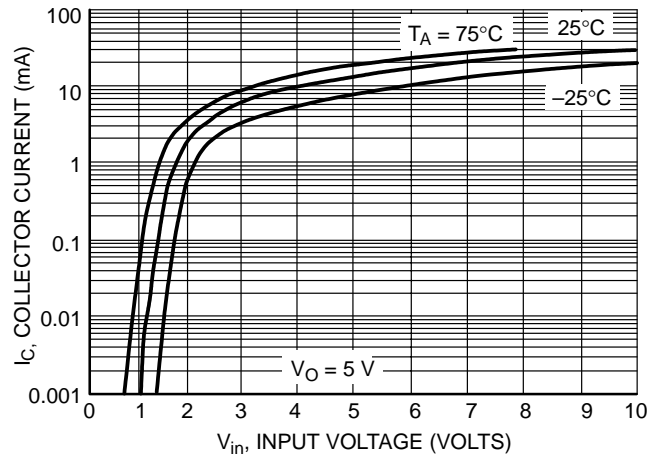


Figure 16. Output Current vs. Input Voltage

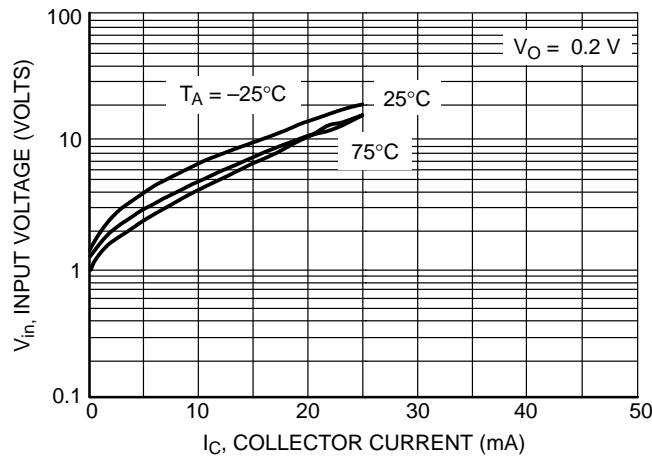


Figure 17. Input Voltage vs. Output Current

MUN211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2114T1

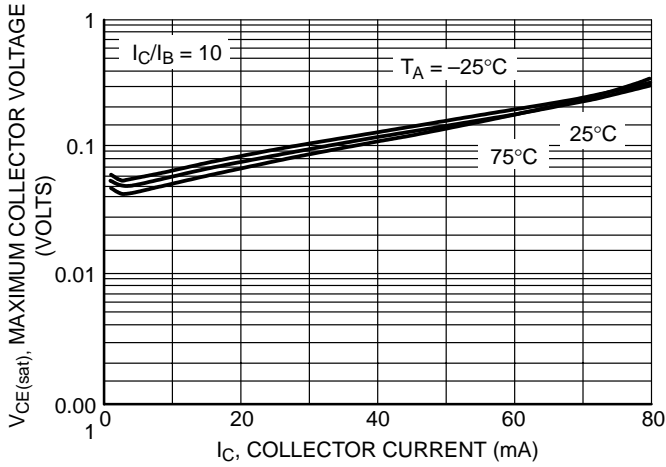


Figure 18. $V_{CE(sat)}$ vs. I_C

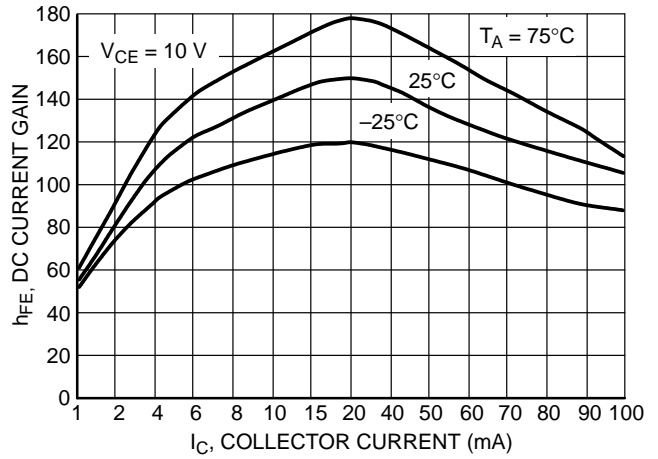


Figure 19. DC Current Gain

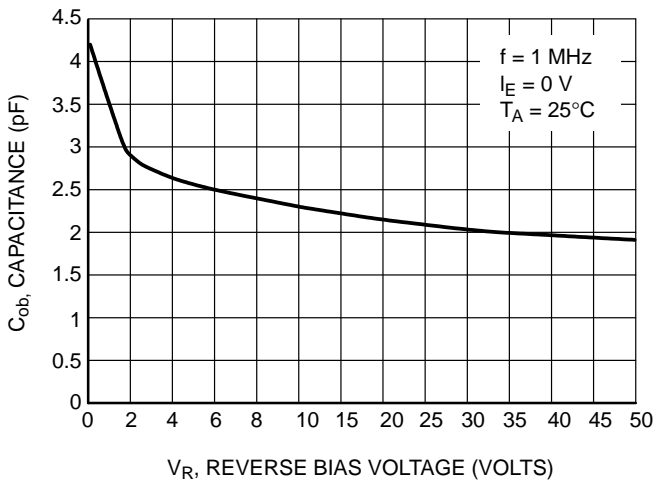


Figure 20. Output Capacitance

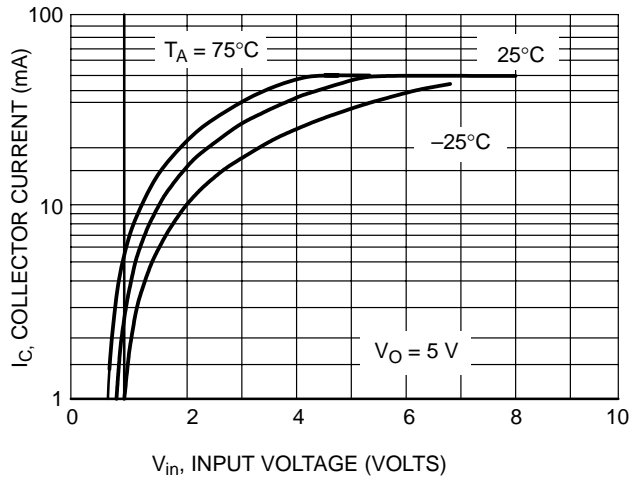


Figure 21. Output Current vs. Input Voltage

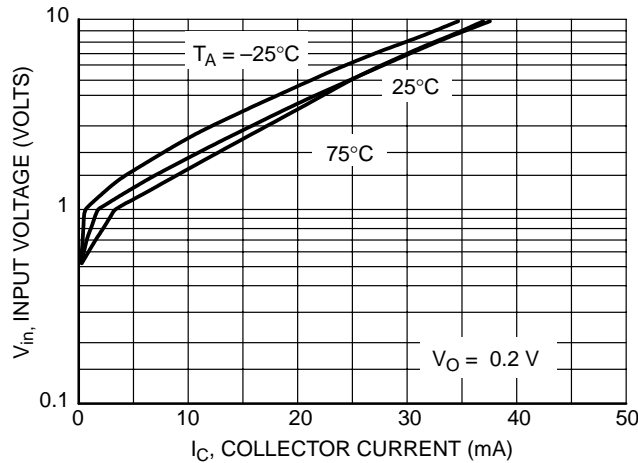


Figure 22. Input Voltage vs. Output Current

MUN211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2131T1

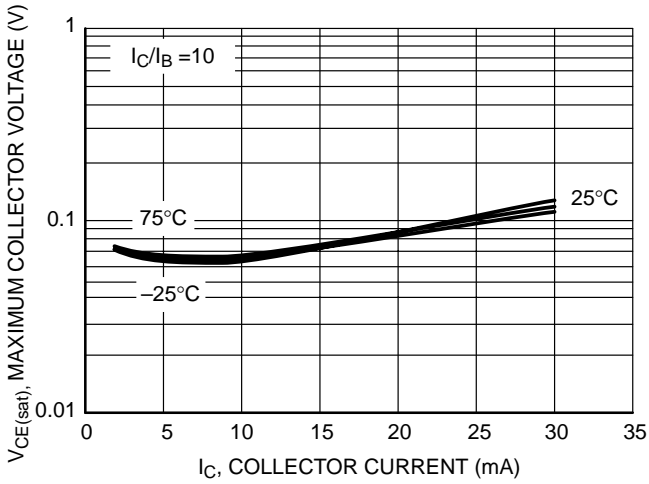


Figure 23. $V_{CE(sat)}$ vs. I_C

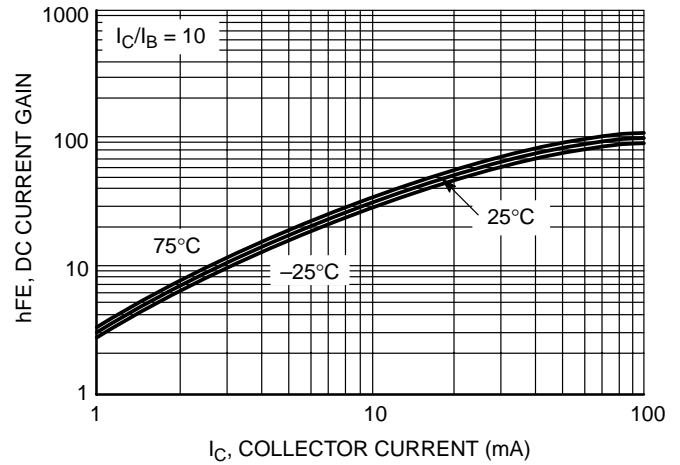


Figure 24. DC Current Gain

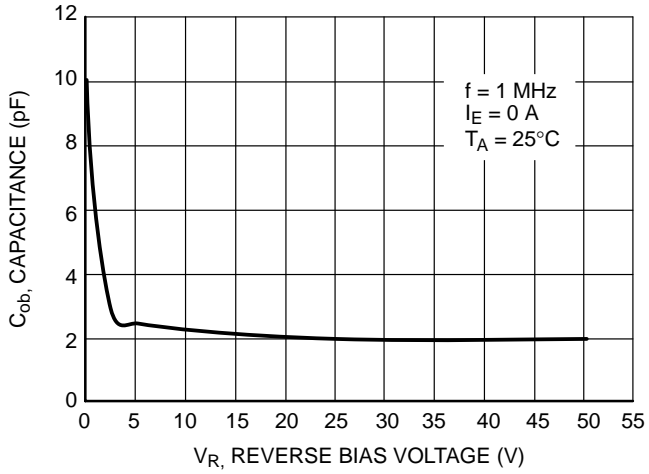


Figure 25. Output Capacitance

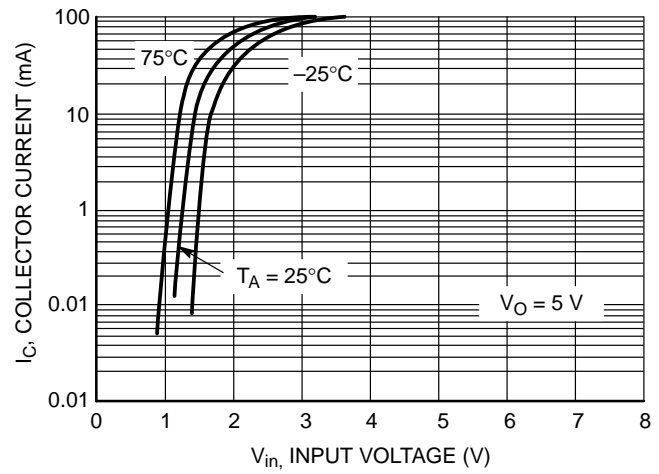


Figure 26. Output Current vs. Input Voltage

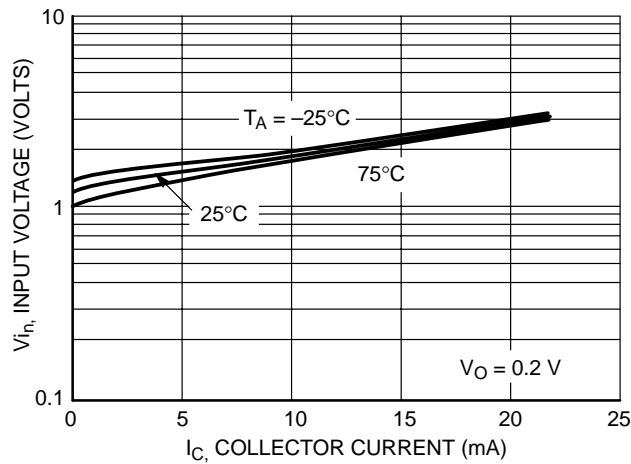


Figure 27. Input Voltage vs. Output Current

MUN211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS — MUN2136T1

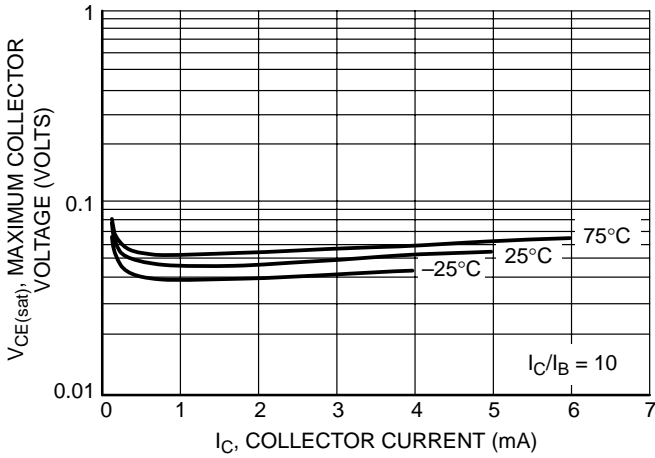


Figure 28. Maximum Collector Voltage versus Collector Current

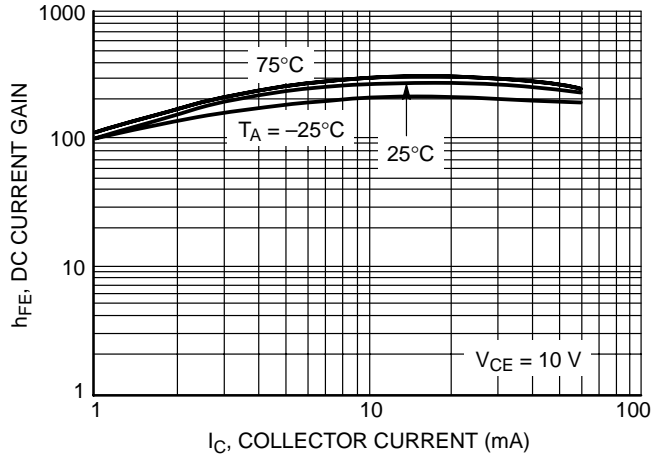


Figure 29. DC Current Gain

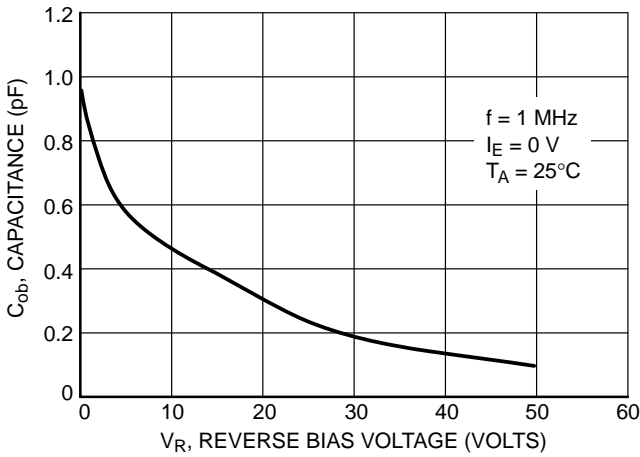


Figure 30. Output Capacitance

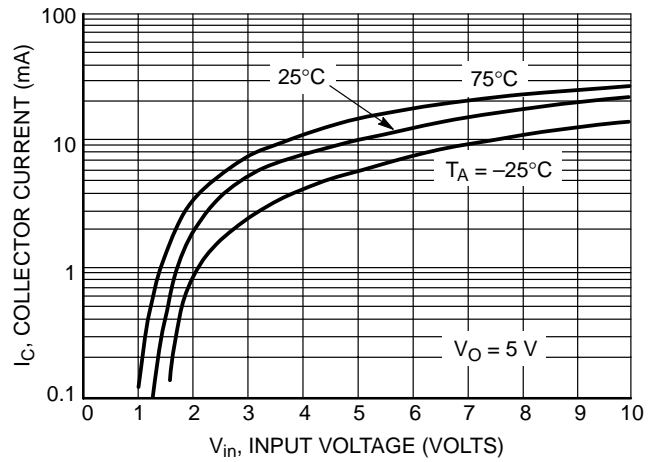


Figure 31. Output Current versus Input Voltage

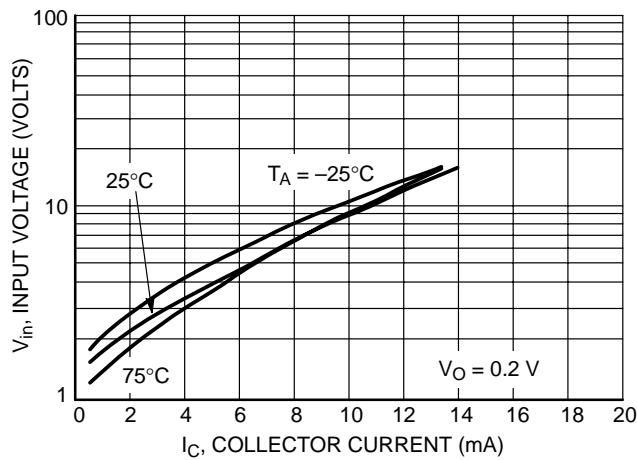


Figure 32. Input Voltage versus Output Current

MUN211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS — MUN2137T1

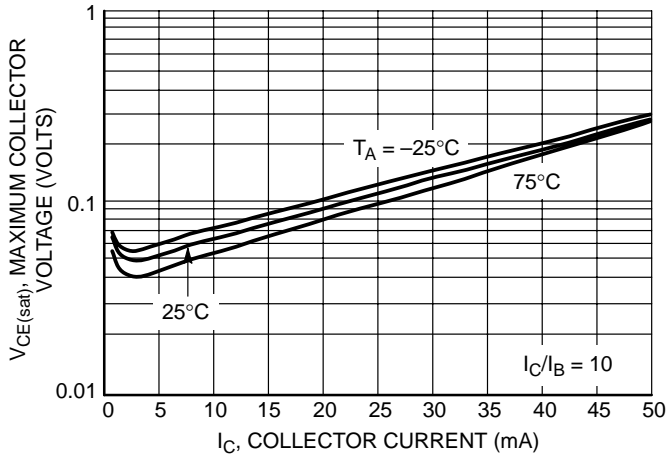


Figure 33. Maximum Collector Voltage versus Collector Current

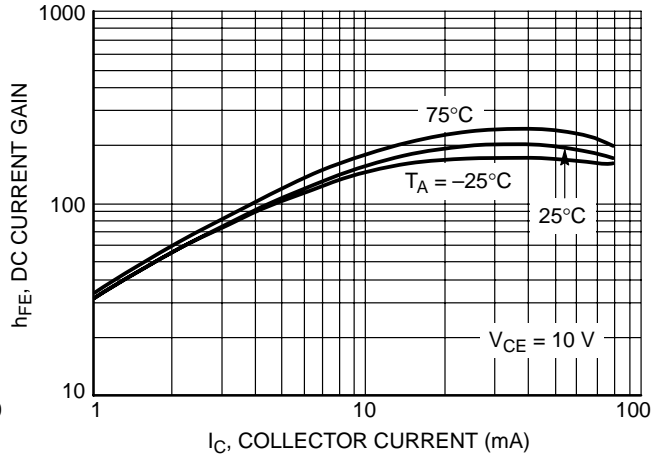


Figure 34. DC Current Gain

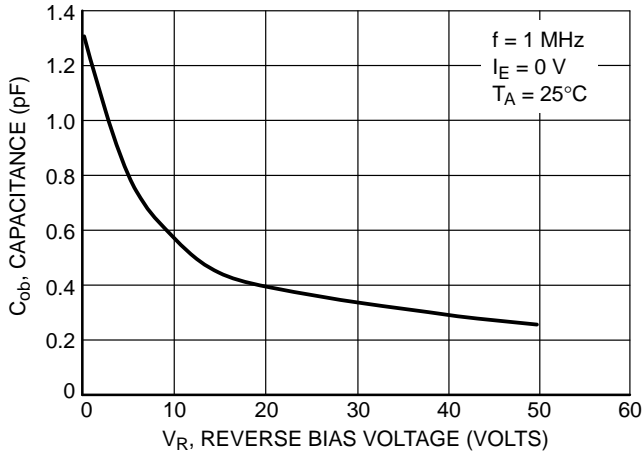


Figure 35. Output Capacitance

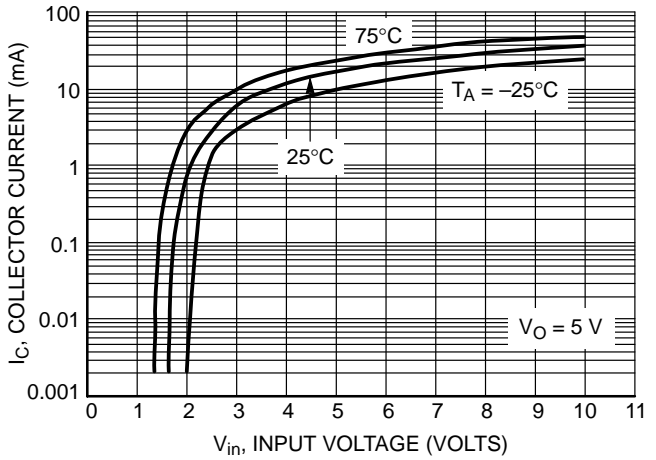


Figure 36. Output Current versus Input Voltage

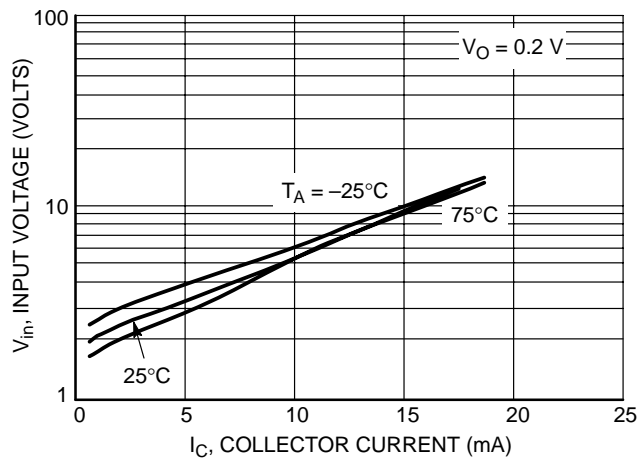


Figure 37. Input Voltage versus Output Current

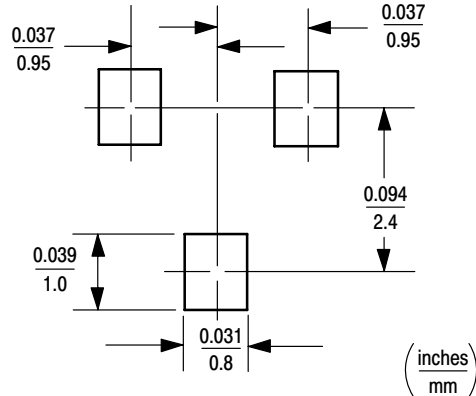
MUN211T1 Series

INFORMATION FOR USING THE SC-59 SURFACE MOUNT PACKAGE

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



SC-59 POWER DISSIPATION

The power dissipation of the SC-59 is a function of the pad size. This can vary from the minimum pad size for soldering to the pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by $T_{J(max)}$, the maximum rated junction temperature of the die, $R_{\theta JA}$, the thermal resistance from the device junction to ambient; and the operating temperature, T_A . Using the values provided on the data sheet, P_D can be calculated as follows.

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into

the equation for an ambient temperature T_A of 25°C, one can calculate the power dissipation of the device which in this case is 338 milliwatts.

$$P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{370^\circ\text{C/W}} = 338 \text{ milliwatts}$$

The 370°C/W assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 338 milliwatts. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using a board material such as Thermal Clad, the power dissipation can be doubled using the same footprint.

SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference should be a maximum of 10°C.

- The soldering temperature and time should not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient should be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling

* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

MUN2111T1 Series

SOLDER STENCIL GUIDELINES

Prior to placing surface mount components onto a printed circuit board, solder paste must be applied to the pads. A solder stencil is required to screen the optimum amount of solder paste onto the footprint. The stencil is made of brass or stainless steel with a typical thickness of 0.008 inches.

The stencil opening size for the surface mounted package should be the same as the pad size on the printed circuit board, i.e., a 1:1 registration.

TYPICAL SOLDER HEATING PROFILE

For any given circuit board, there will be a group of control settings that will give the desired heat pattern. The operator must set temperatures for several heating zones, and a figure for belt speed. Taken together, these control settings make up a heating “profile” for that particular circuit board. On machines controlled by a computer, the computer remembers these profiles from one operating session to the next. Figure 7 shows a typical heating profile for use when soldering a surface mount device to a printed circuit board. This profile will vary among soldering systems but it is a good starting point. Factors that can affect the profile include the type of soldering system in use, density and types of components on the board, type of solder used, and the type of board or substrate material being used. This profile shows temperature versus time.

The line on the graph shows the actual temperature that might be experienced on the surface of a test board at or near a central solder joint. The two profiles are based on a high density and a low density board. The Vitronics SMD310 convection/infrared reflow soldering system was used to generate this profile. The type of solder used was 62/36/2 Tin Lead Silver with a melting point between 177–189°C. When this type of furnace is used for solder reflow work, the circuit boards and solder joints tend to heat first. The components on the board are then heated by conduction. The circuit board, because it has a large surface area, absorbs the thermal energy more efficiently, then distributes this energy to the components. Because of this effect, the main body of a component may be up to 30 degrees cooler than the adjacent solder joints.

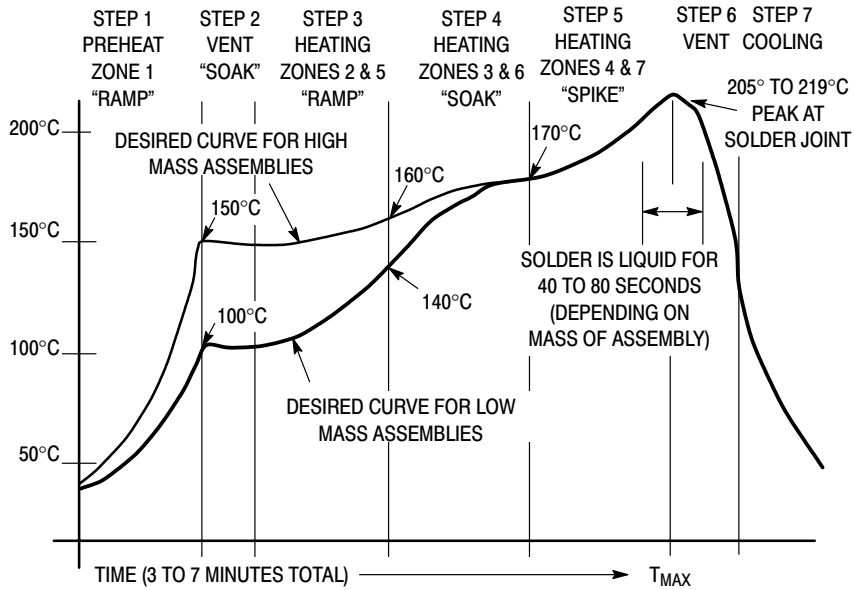
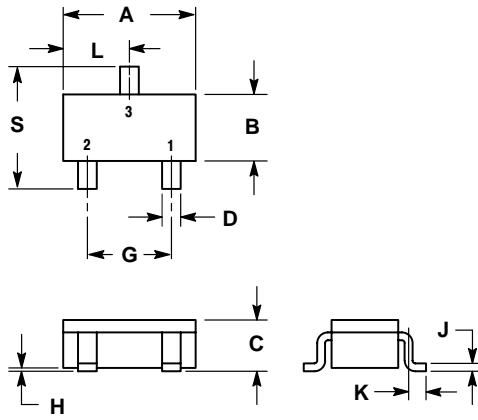


Figure 38. Typical Solder Heating Profile

MUN2111T1 Series

PACKAGE DIMENSIONS

SC-59
CASE 318D-04
ISSUE F



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.70	3.10	0.1063	0.1220
B	1.30	1.70	0.0512	0.0669
C	1.00	1.30	0.0394	0.0511
D	0.35	0.50	0.0138	0.0196
G	1.70	2.10	0.0670	0.0826
H	0.013	0.100	0.0005	0.0040
J	0.09	0.18	0.0034	0.0070
K	0.20	0.60	0.0079	0.0236
L	1.25	1.65	0.0493	0.0649
S	2.50	3.00	0.0985	0.1181


STYLE 1:

- PIN 1. EMITTER
- BASE
- COLLECTOR

Notes

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